

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 824.2 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM850_open_H Scan/L ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.269 A/m

Probe Modulation Factor = 2.790

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.060 A/m; Power Drift = -0.04 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

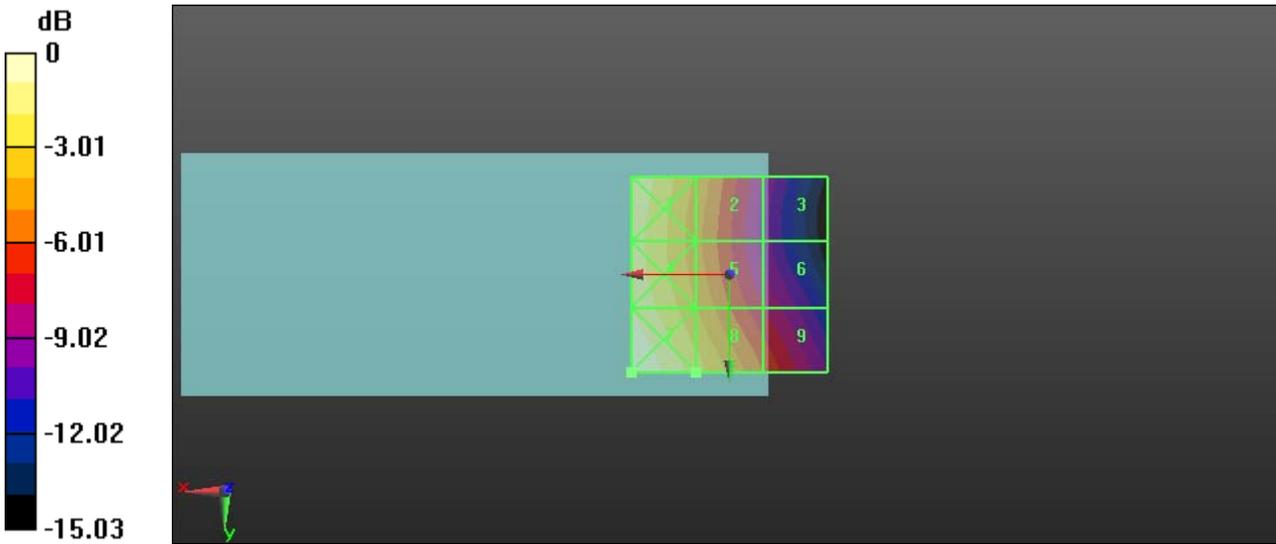
Grid 1 0.320 M4	Grid 2 0.222 M4	Grid 3 0.128 M4
Grid 4 0.321 M4	Grid 5 0.229 M4	Grid 6 0.145 M4
Grid 7 0.364 M4	Grid 8 0.269 M4	Grid 9 0.181 M4

Cursor:

Total = 0.364 A/m

H Category: M4

Location: 25, 25, 8.7 mm



0 dB = 0.360A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 836.6 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM850_open_H Scan/M ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.269 A/m

Probe Modulation Factor = 2.790

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.062 A/m; Power Drift = 0.16 dB

Hearing Aid Near-Field Category: **M4 (AWF -5 dB)**

Peak H-field in A/m

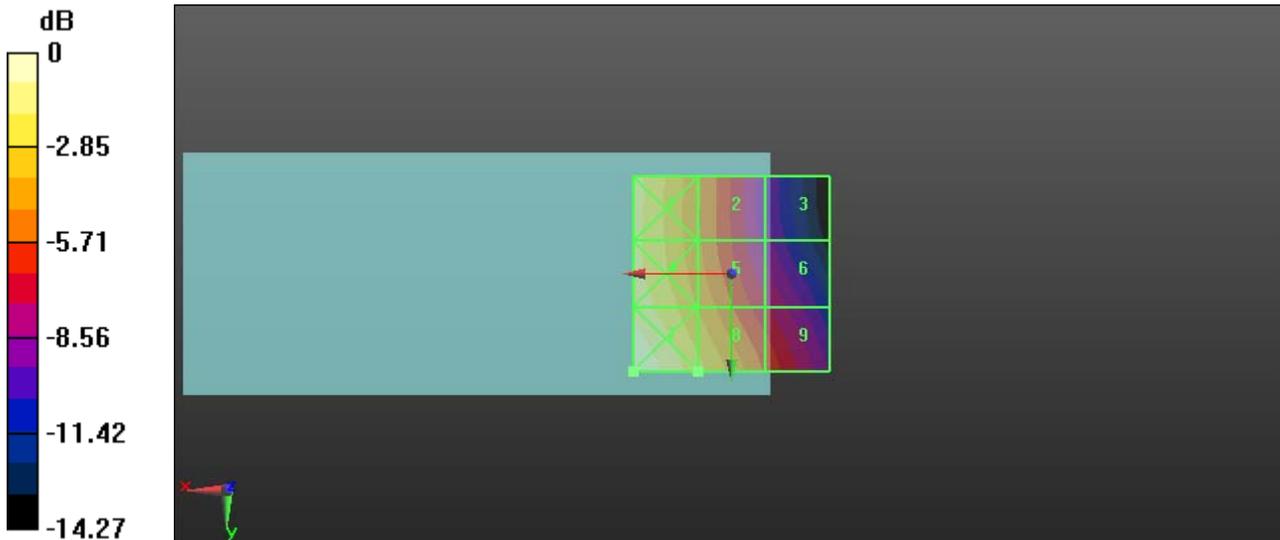
Grid 1 0.307 M4	Grid 2 0.213 M4	Grid 3 0.128 M4
Grid 4 0.317 M4	Grid 5 0.231 M4	Grid 6 0.154 M4
Grid 7 0.358 M4	Grid 8 0.269 M4	Grid 9 0.185 M4

Cursor:

Total = 0.358 A/m

H Category: M4

Location: 25, 25, 8.7 mm



0 dB = 0.360 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 848.8 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM850_open_H Scan/H ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.252 A/m

Probe Modulation Factor = 2.790

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.061 A/m; Power Drift = -0.03 dB

Hearing Aid Near-Field Category: **M4 (AWF -5 dB)**

Peak H-field in A/m

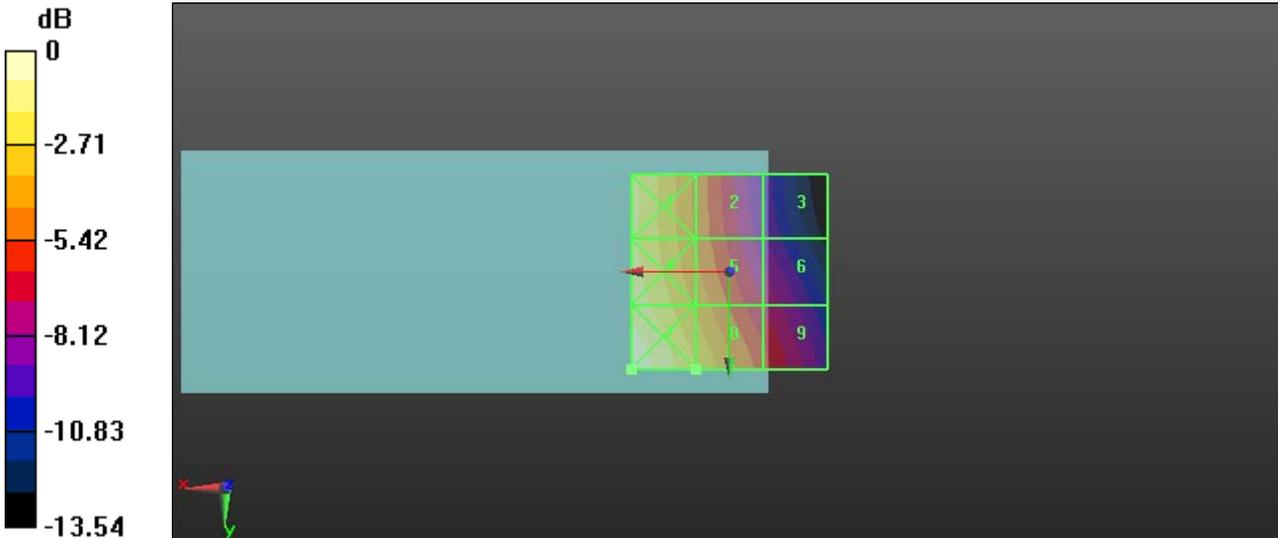
Grid 1 0.289 M4	Grid 2 0.200 M4	Grid 3 0.126 M4
Grid 4 0.299 M4	Grid 5 0.219 M4	Grid 6 0.149 M4
Grid 7 0.335 M4	Grid 8 0.252 M4	Grid 9 0.173 M4

Cursor:

Total = 0.335 A/m

H Category: M4

Location: 25, 25, 8.7 mm



0 dB = 0.340 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 824.2 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011

- Sensor-Surface: (Fix Surface)

- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010

- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB

- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM850_closed_H Scan/L ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.325 A/m

Probe Modulation Factor = 2.790

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.084 A/m; Power Drift = -0.0035 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

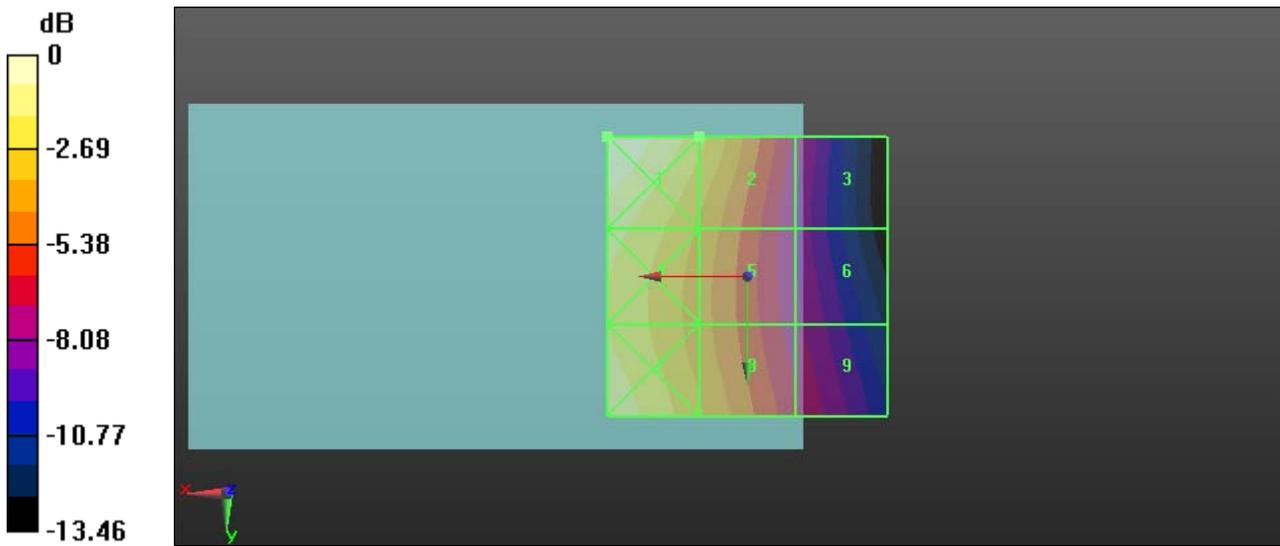
Grid 1 0.430 M4	Grid 2 0.325 M4	Grid 3 0.182 M4
Grid 4 0.369 M4	Grid 5 0.279 M4	Grid 6 0.177 M4
Grid 7 0.377 M4	Grid 8 0.289 M4	Grid 9 0.194 M4

Cursor:

Total = 0.430 A/m

H Category: M4

Location: 25, -25, 8.7 mm



Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 836.6 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM850_closed_H Scan/M ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.354 A/m

Probe Modulation Factor = 2.790

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.092 A/m; Power Drift = 0.10 dB

Hearing Aid Near-Field Category: **M4 (AWF -5 dB)**

Peak H-field in A/m

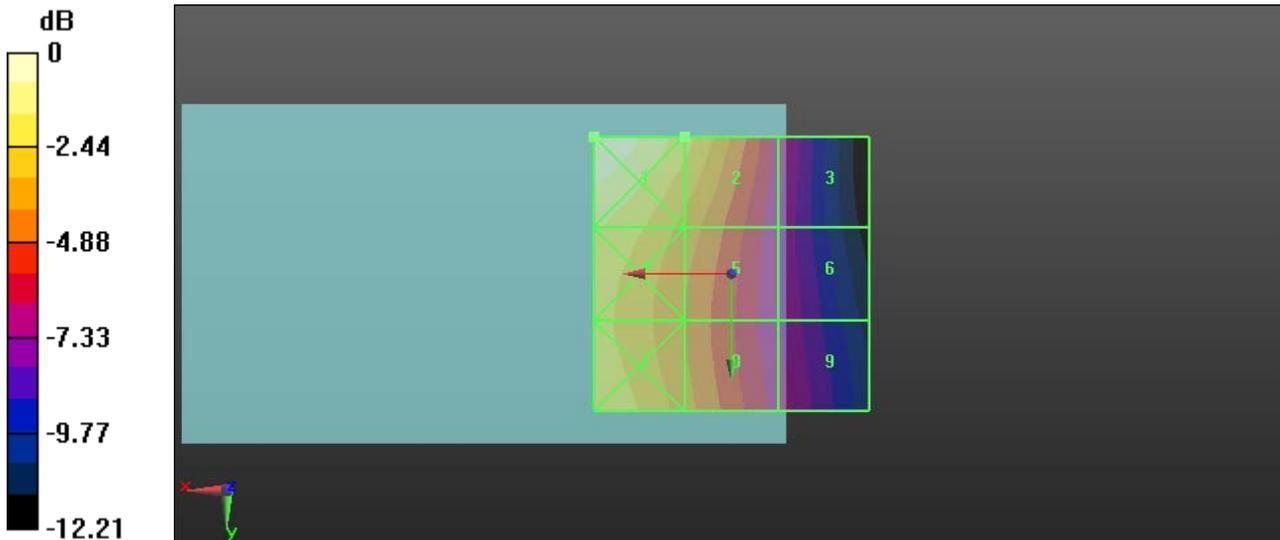
Grid 1 0.449 M4	Grid 2 0.354 M4	Grid 3 0.206 M4
Grid 4 0.379 M4	Grid 5 0.300 M4	Grid 6 0.196 M4
Grid 7 0.375 M4	Grid 8 0.295 M4	Grid 9 0.204 M4

Cursor:

Total = 0.449 A/m

H Category: M4

Location: 25, -25, 8.7 mm



0 dB = 0.450 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM850; Frequency: 848.8 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM850_closed_H Scan/H ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.295 A/m

Probe Modulation Factor = 2.790

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.086 A/m; Power Drift = 0.10 dB

Hearing Aid Near-Field Category: **M4 (AWF -5 dB)**

Peak H-field in A/m

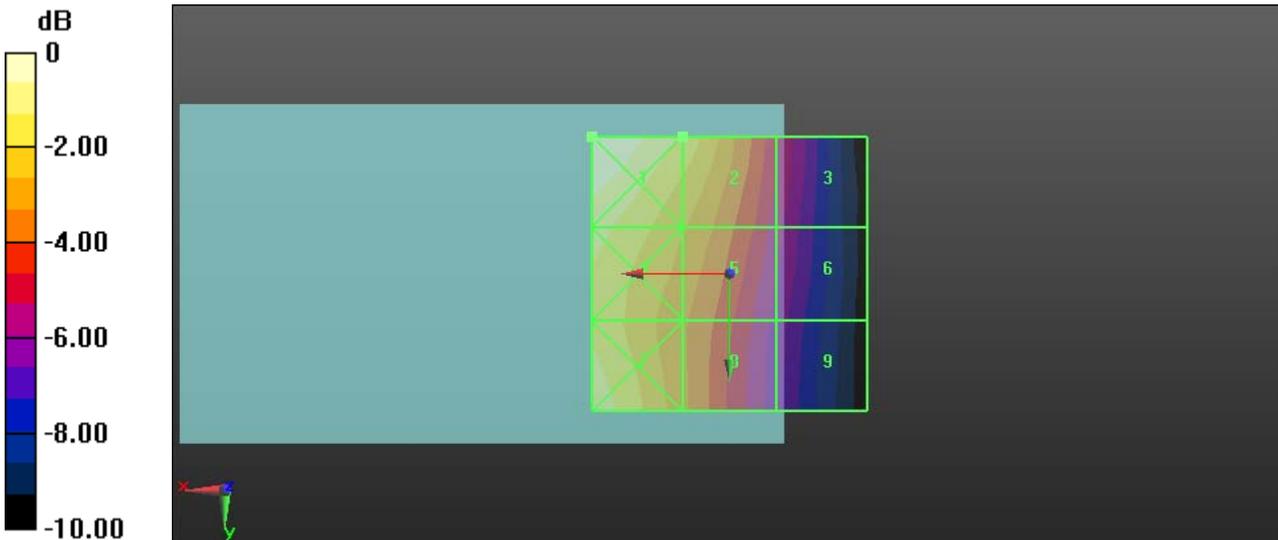
Grid 1 0.354 M4	Grid 2 0.295 M4	Grid 3 0.192 M4
Grid 4 0.312 M4	Grid 5 0.260 M4	Grid 6 0.183 M4
Grid 7 0.316 M4	Grid 8 0.244 M4	Grid 9 0.171 M4

Cursor:

Total = 0.354 A/m

H Category: M4

Location: 25, -25, 8.7 mm



0 dB = 0.350 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011

- Sensor-Surface: (Fix Surface)

- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010

- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB

- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM1900_open_H Scan/L ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.196 A/m

Probe Modulation Factor = 2.840

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.069 A/m; Power Drift = -5.3e-005 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

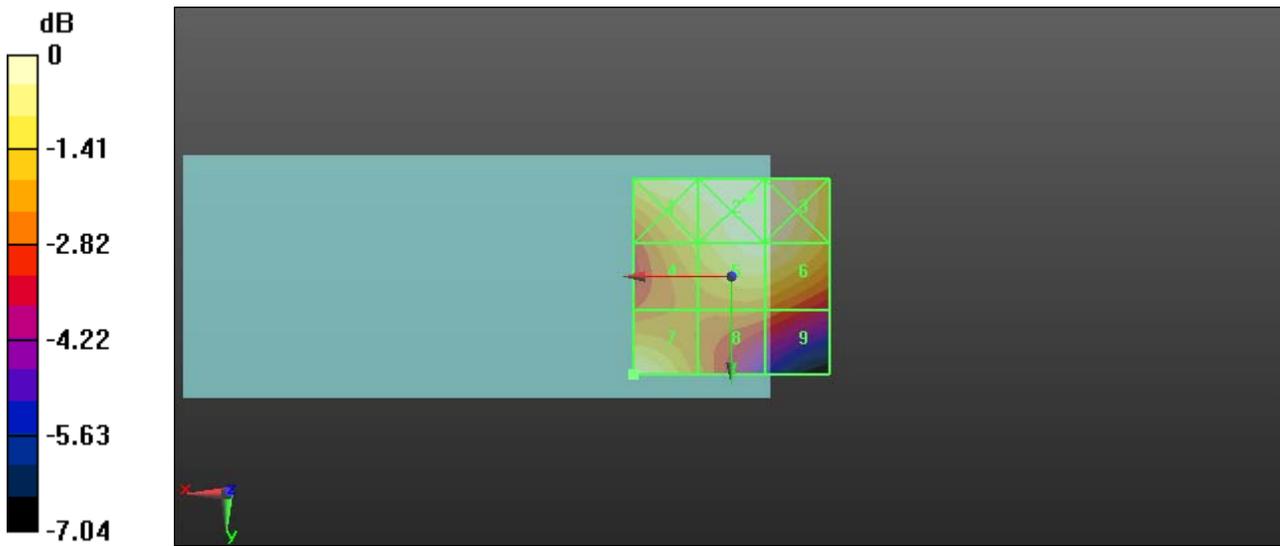
Grid 1 0.195 M3	Grid 2 0.199 M3	Grid 3 0.198 M3
Grid 4 0.174 M3	Grid 5 0.194 M3	Grid 6 0.194 M3
Grid 7 0.196 M3	Grid 8 0.157 M3	Grid 9 0.152 M3

Cursor:

Total = 0.199 A/m

H Category: M3

Location: -5, -20, 8.7 mm



0 dB = 0.200A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1880 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM1900_open_H Scan/M ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.211 A/m

Probe Modulation Factor = 2.840

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.073 A/m; Power Drift = 0.12 dB

Hearing Aid Near-Field Category: **M3 (AWF -5 dB)**

Peak H-field in A/m

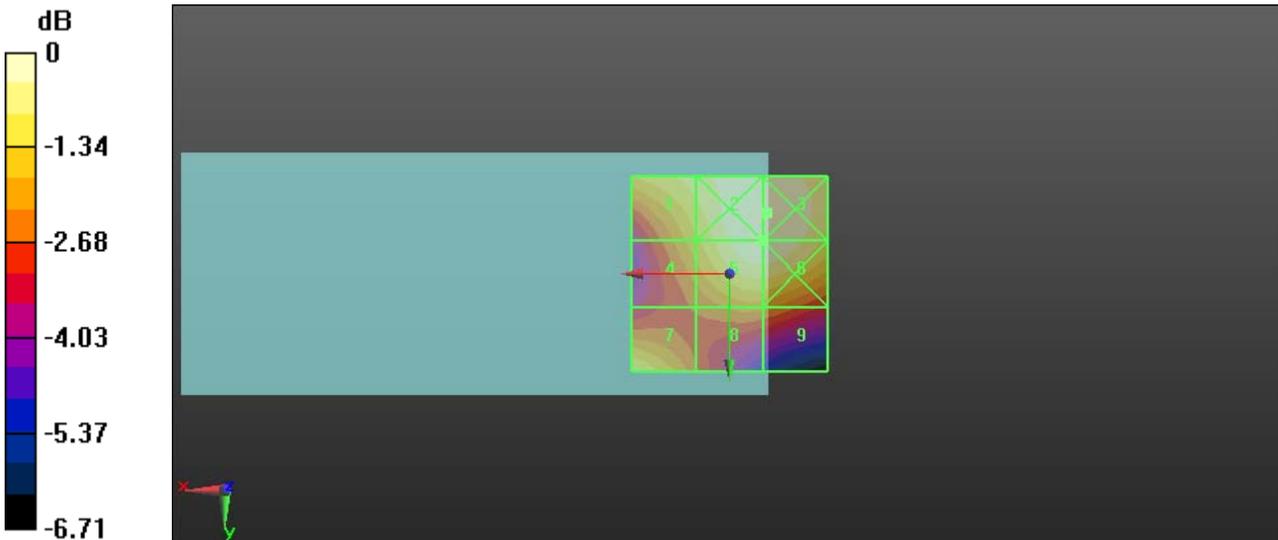
Grid 1 0.195 M3	Grid 2 0.214 M3	Grid 3 0.214 M3
Grid 4 0.178 M3	Grid 5 0.211 M3	Grid 6 0.211 M3
Grid 7 0.195 M3	Grid 8 0.167 M3	Grid 9 0.165 M3

Cursor:

Total = 0.214 A/m

H Category: M3

Location: -9.5, -15.5, 8.7 mm



0 dB = 0.210 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM1900_open_H Scan/H ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.188 A/m

Probe Modulation Factor = 2.840

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.068 A/m; Power Drift = 0.0038 dB

Hearing Aid Near-Field Category: **M3 (AWF -5 dB)**

Peak H-field in A/m

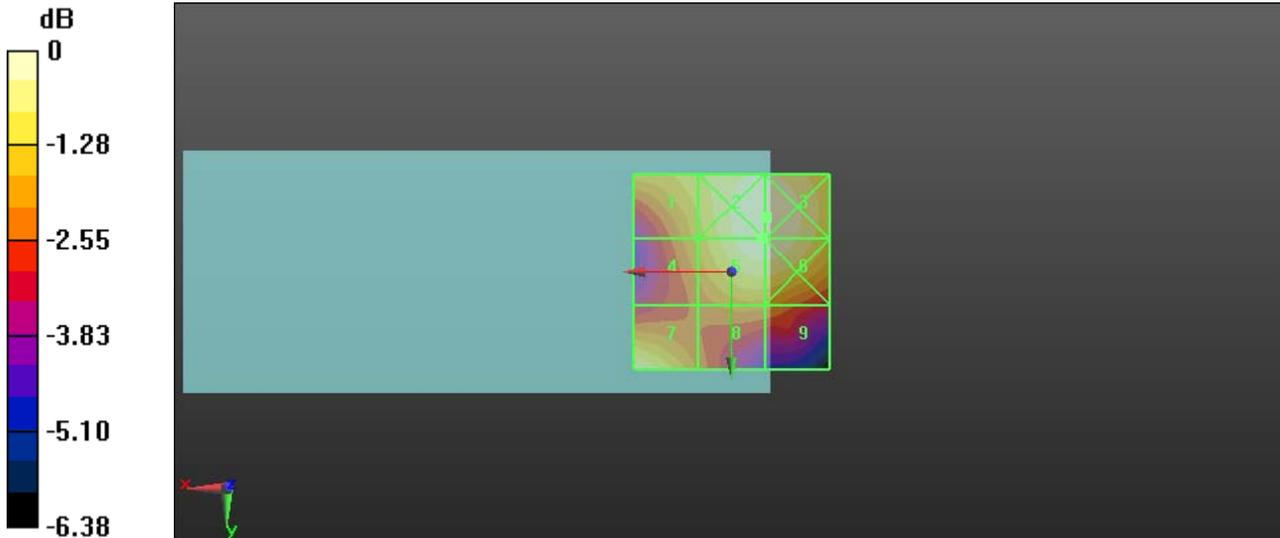
Grid 1 0.171 M3	Grid 2 0.190 M3	Grid 3 0.190 M3
Grid 4 0.160 M3	Grid 5 0.188 M3	Grid 6 0.188 M3
Grid 7 0.186 M3	Grid 8 0.153 M3	Grid 9 0.152 M3

Cursor:

Total = 0.190 A/m

H Category: M3

Location: -9, -14, 8.7 mm



0 dB = 0.190A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011

- Sensor-Surface: (Fix Surface)

- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010

- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB

- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM1900_closed_H Scan/L ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.169 A/m

Probe Modulation Factor = 2.840

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.055 A/m; Power Drift = 0.08 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

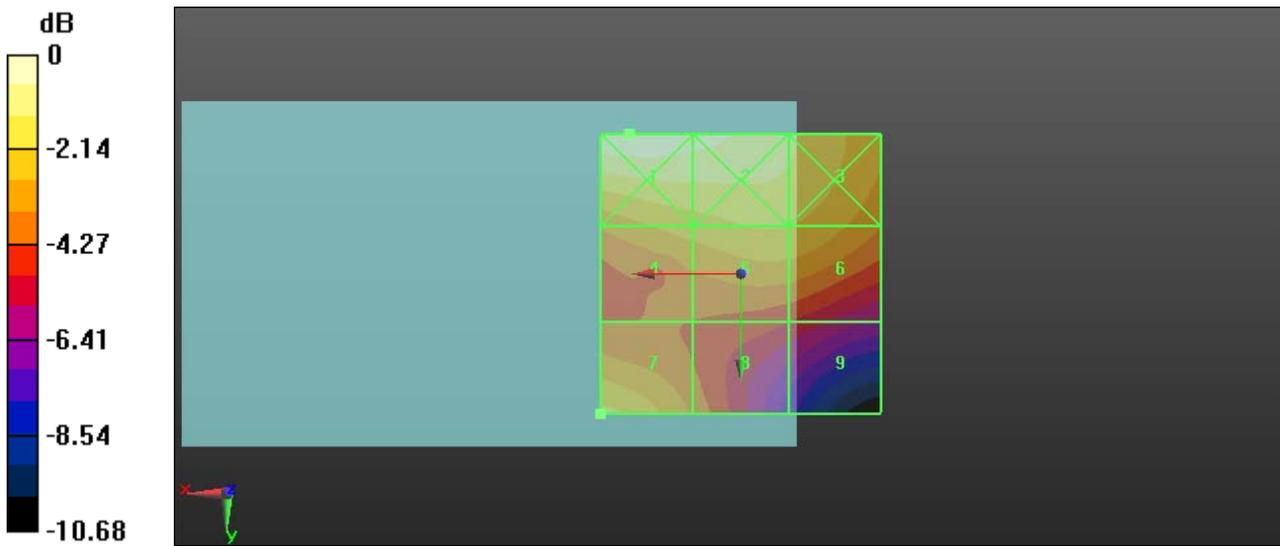
Grid 1 0.209 M3	Grid 2 0.201 M3	Grid 3 0.181 M3
Grid 4 0.157 M3	Grid 5 0.165 M3	Grid 6 0.164 M3
Grid 7 0.169 M3	Grid 8 0.138 M4	Grid 9 0.119 M4

Cursor:

Total = 0.209 A/m

H Category: M3

Location: 20, -25, 8.7 mm



0 dB = 0.210A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1880 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM1900_closed_H Scan/M ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.174 A/m

Probe Modulation Factor = 2.840

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.055 A/m; Power Drift = -0.03 dB

Hearing Aid Near-Field Category: **M3 (AWF -5 dB)**

Peak H-field in A/m

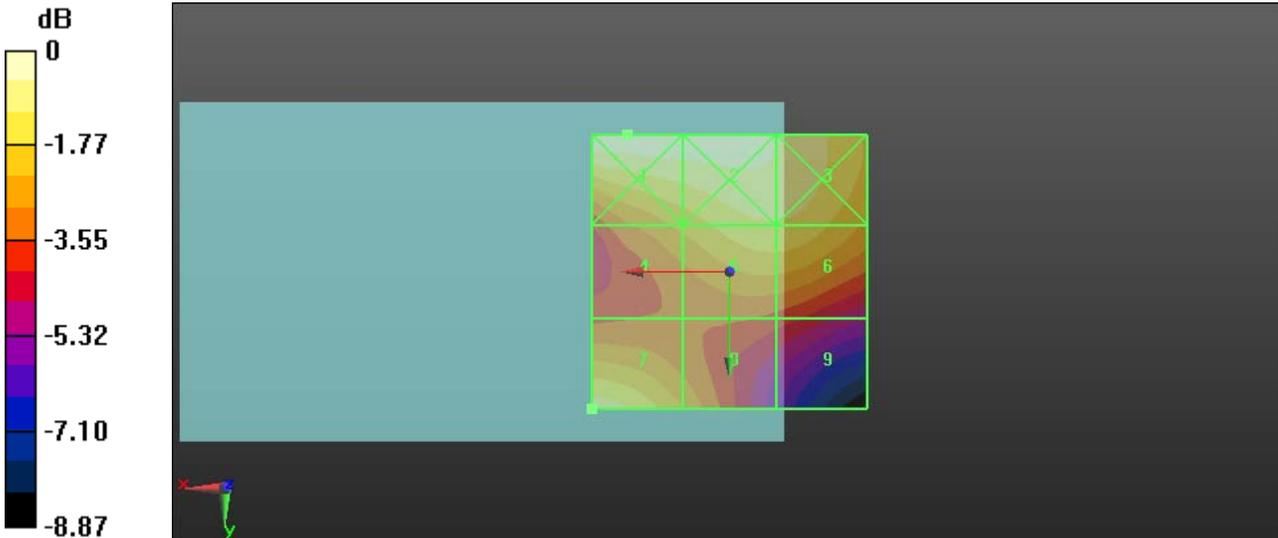
Grid 1 0.190 M3	Grid 2 0.188 M3	Grid 3 0.177 M3
Grid 4 0.148 M3	Grid 5 0.165 M3	Grid 6 0.165 M3
Grid 7 0.174 M3	Grid 8 0.145 M3	Grid 9 0.123 M4

Cursor:

Total = 0.190 A/m

H Category: M3

Location: 18.5, -25, 8.7 mm



0 dB = 0.190A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: GSM1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.00018

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

GSM1900_closed_H Scan/H ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.173 A/m

Probe Modulation Factor = 2.840

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.051 A/m; Power Drift = -0.05 dB

Hearing Aid Near-Field Category: **M3 (AWF -5 dB)**

Peak H-field in A/m

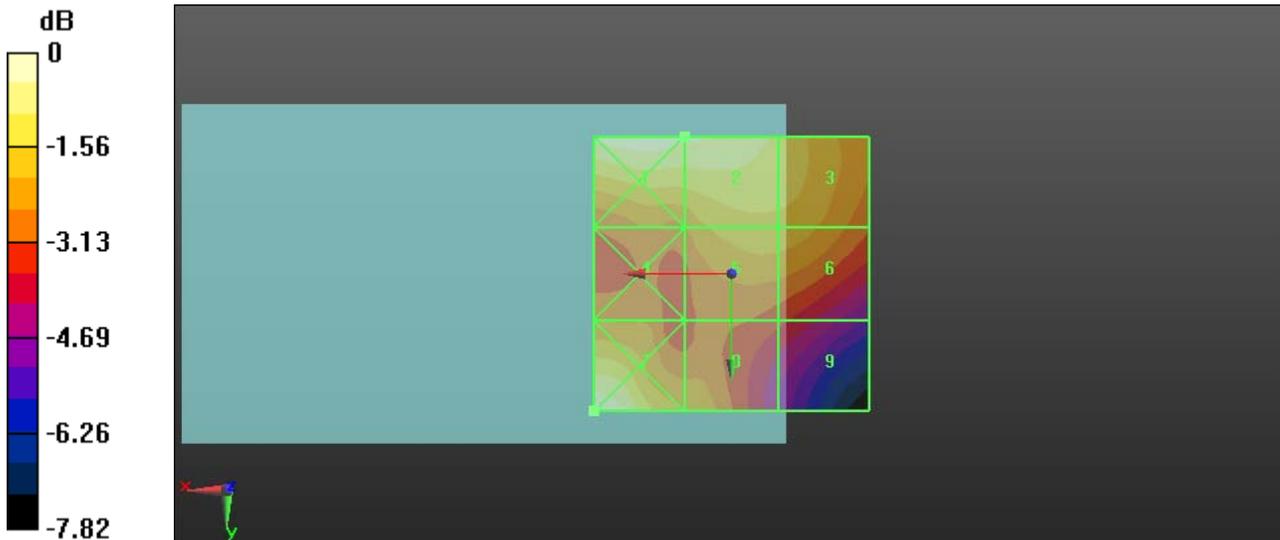
Grid 1 0.177 M3	Grid 2 0.173 M3	Grid 3 0.157 M3
Grid 4 0.134 M4	Grid 5 0.147 M3	Grid 6 0.147 M3
Grid 7 0.178 M3	Grid 8 0.142 M3	Grid 9 0.121 M4

Cursor:

Total = 0.178 A/m

H Category: M3

Location: 25, 25, 8.7 mm



0 dB = 0.180 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 824.7 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 Cell band_open_H Scan/L ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.090 A/m

Probe Modulation Factor = 0.960

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.061 A/m; Power Drift = 0.01 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

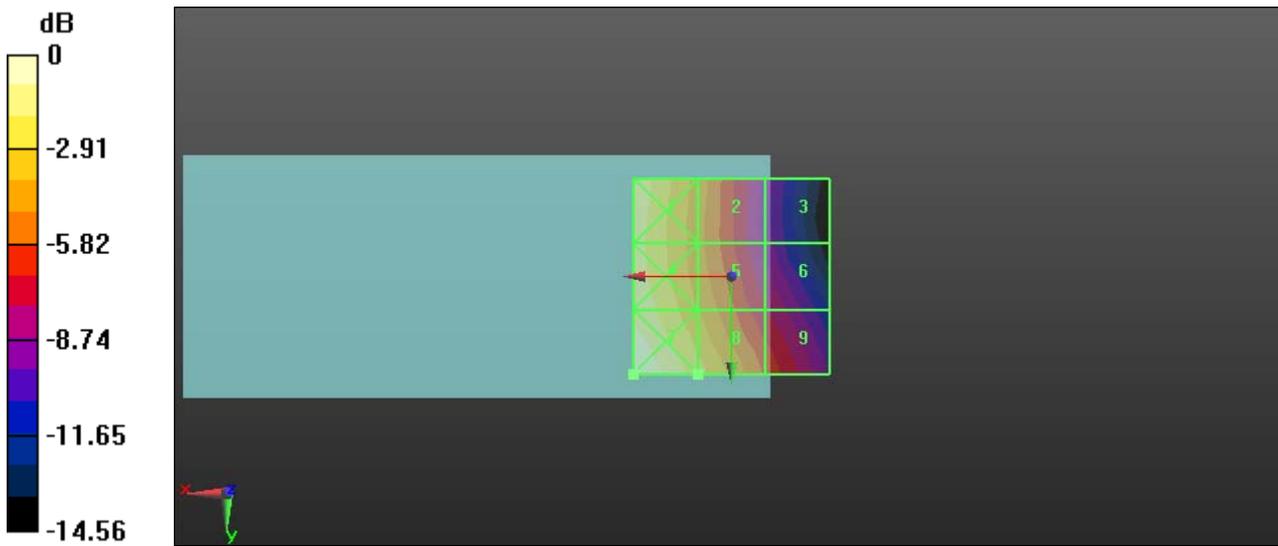
Grid 1 0.106 M4	Grid 2 0.073 M4	Grid 3 0.043 M4
Grid 4 0.105 M4	Grid 5 0.077 M4	Grid 6 0.050 M4
Grid 7 0.120 M4	Grid 8 0.090 M4	Grid 9 0.061 M4

Cursor:

Total = 0.120 A/m

H Category: M4

Location: 25, 25, 8.7 mm



0 dB = 0.120A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 836.52 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 Cell band_open_H Scan/M ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.089 A/m

Probe Modulation Factor = 0.960

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.062 A/m; Power Drift = 0.11 dB

Hearing Aid Near-Field Category: **M4 (AWF 0 dB)**

Peak H-field in A/m

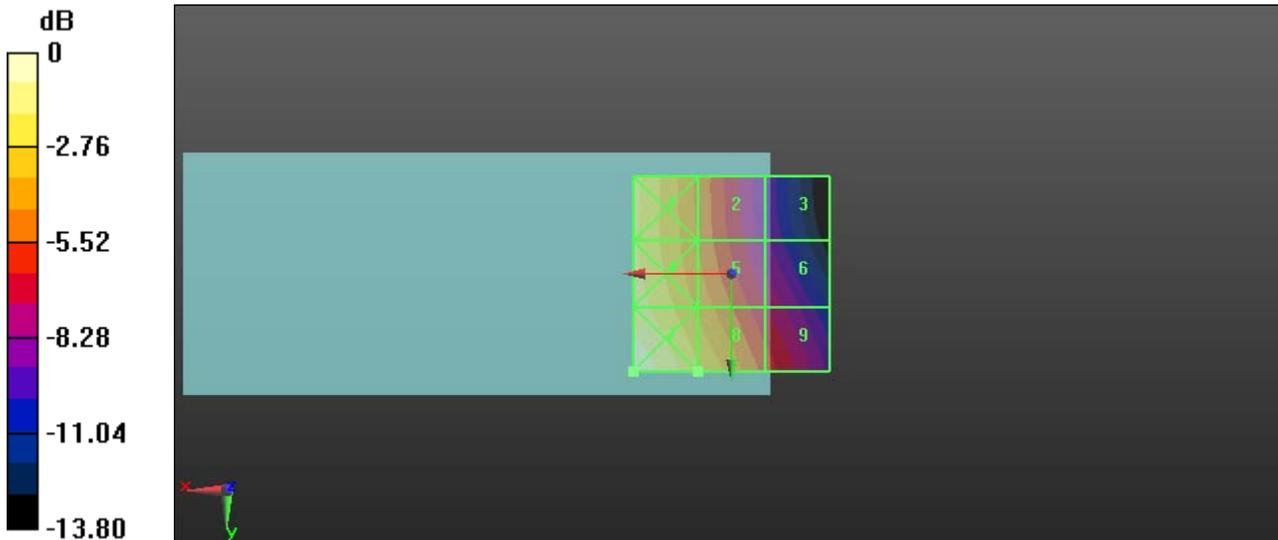
Grid 1 0.102 M4	Grid 2 0.071 M4	Grid 3 0.044 M4
Grid 4 0.104 M4	Grid 5 0.077 M4	Grid 6 0.052 M4
Grid 7 0.118 M4	Grid 8 0.089 M4	Grid 9 0.062 M4

Cursor:

Total = 0.118 A/m

H Category: M4

Location: 25, 25, 8.7 mm



0 dB = 0.120A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 848.31 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 Cell band_open_H Scan/H ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.084 A/m

Probe Modulation Factor = 0.960

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.061 A/m; Power Drift = 0.09 dB

Hearing Aid Near-Field Category: **M4 (AWF 0 dB)**

Peak H-field in A/m

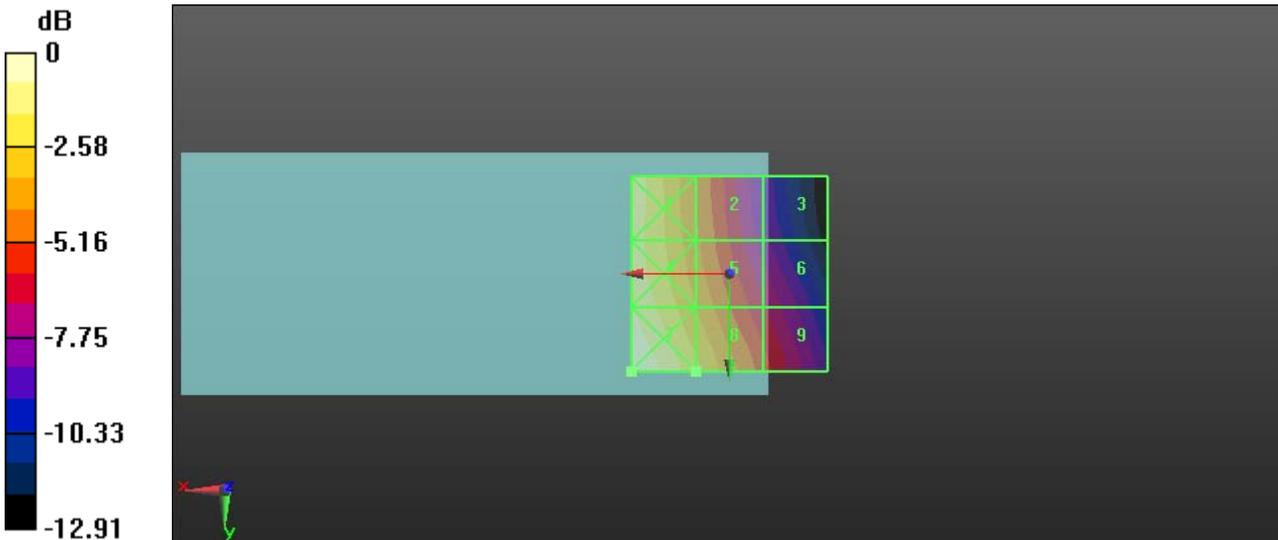
Grid 1 0.097 M4	Grid 2 0.068 M4	Grid 3 0.043 M4
Grid 4 0.100 M4	Grid 5 0.074 M4	Grid 6 0.051 M4
Grid 7 0.111 M4	Grid 8 0.084 M4	Grid 9 0.058 M4

Cursor:

Total = 0.111 A/m

H Category: M4

Location: 25, 25, 8.7 mm



0 dB = 0.110A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 824.7 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 Cell band_closed_H Scan/L ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.126 A/m

Probe Modulation Factor = 0.960

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.089 A/m; Power Drift = -0.15 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

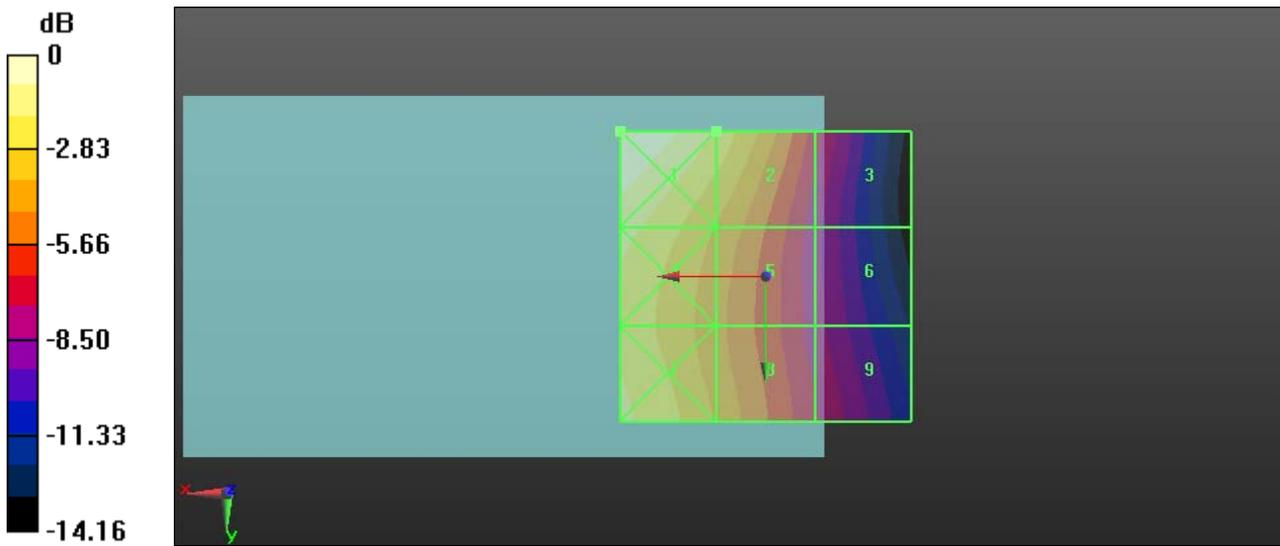
Grid 1 0.164 M4	Grid 2 0.126 M4	Grid 3 0.071 M4
Grid 4 0.136 M4	Grid 5 0.103 M4	Grid 6 0.064 M4
Grid 7 0.133 M4	Grid 8 0.103 M4	Grid 9 0.068 M4

Cursor:

Total = 0.164 A/m

H Category: M4

Location: 25, -25, 8.7 mm



0 dB = 0.160 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 836.52 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 Cell band_closed_H Scan/M ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.130 A/m

Probe Modulation Factor = 0.960

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.098 A/m; Power Drift = -0.10 dB

Hearing Aid Near-Field Category: **M4 (AWF 0 dB)**

Peak H-field in A/m

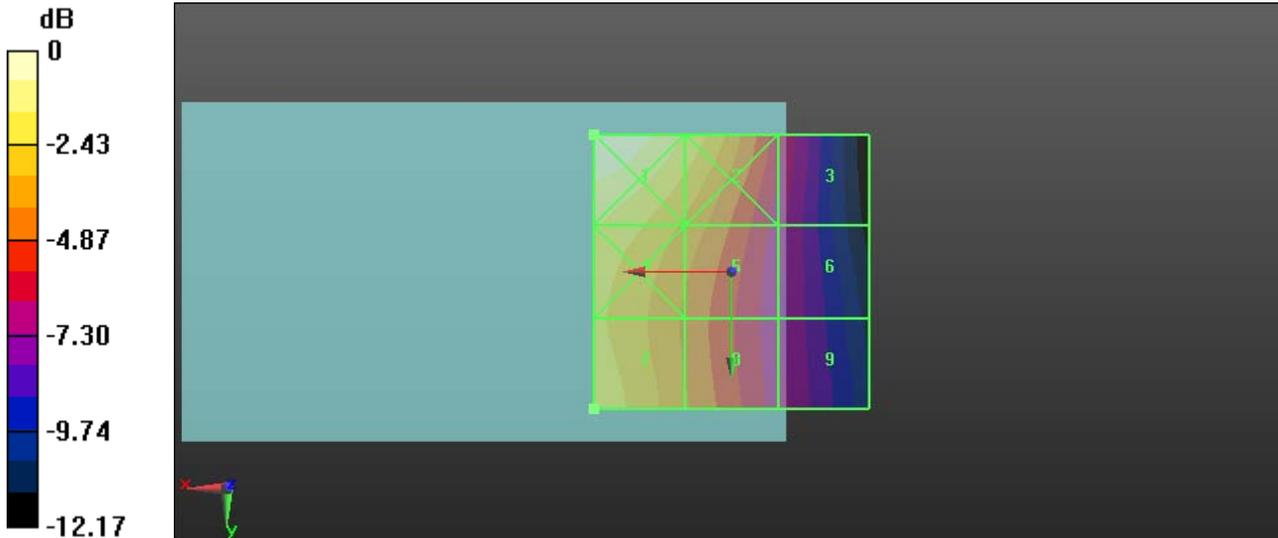
Grid 1 0.163 M4	Grid 2 0.132 M4	Grid 3 0.079 M4
Grid 4 0.135 M4	Grid 5 0.108 M4	Grid 6 0.072 M4
Grid 7 0.130 M4	Grid 8 0.102 M4	Grid 9 0.072 M4

Cursor:

Total = 0.163 A/m

H Category: M4

Location: 25, -25, 8.7 mm



0 dB = 0.160 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA Cell Band for Palm; Frequency: 848.31 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 Cell band_closed_H Scan/H ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.103 A/m

Probe Modulation Factor = 0.960

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.086 A/m; Power Drift = -0.48 dB

Hearing Aid Near-Field Category: **M4 (AWF 0 dB)**

Peak H-field in A/m

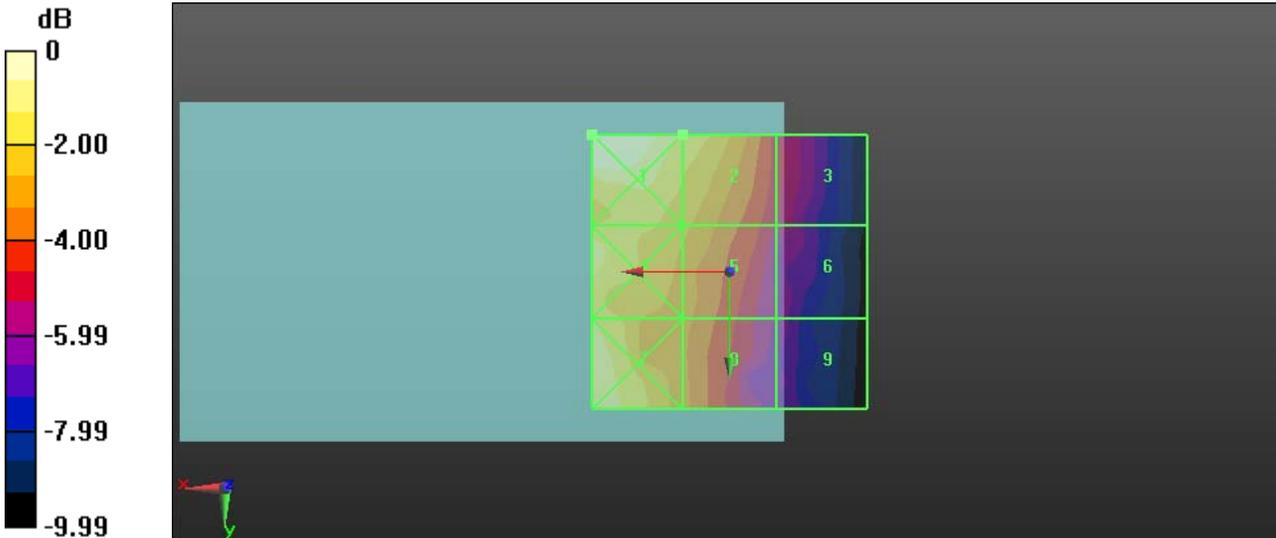
Grid 1 0.122 M4	Grid 2 0.103 M4	Grid 3 0.068 M4
Grid 4 0.105 M4	Grid 5 0.090 M4	Grid 6 0.065 M4
Grid 7 0.109 M4	Grid 8 0.084 M4	Grid 9 0.060 M4

Cursor:

Total = 0.122 A/m

H Category: M4

Location: 25, -25, 8.7 mm



0 dB = 0.120 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011

- Sensor-Surface: (Fix Surface)

- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010

- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB

- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 PCS band_open_H Scan/L ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.091 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.092 A/m; Power Drift = -0.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

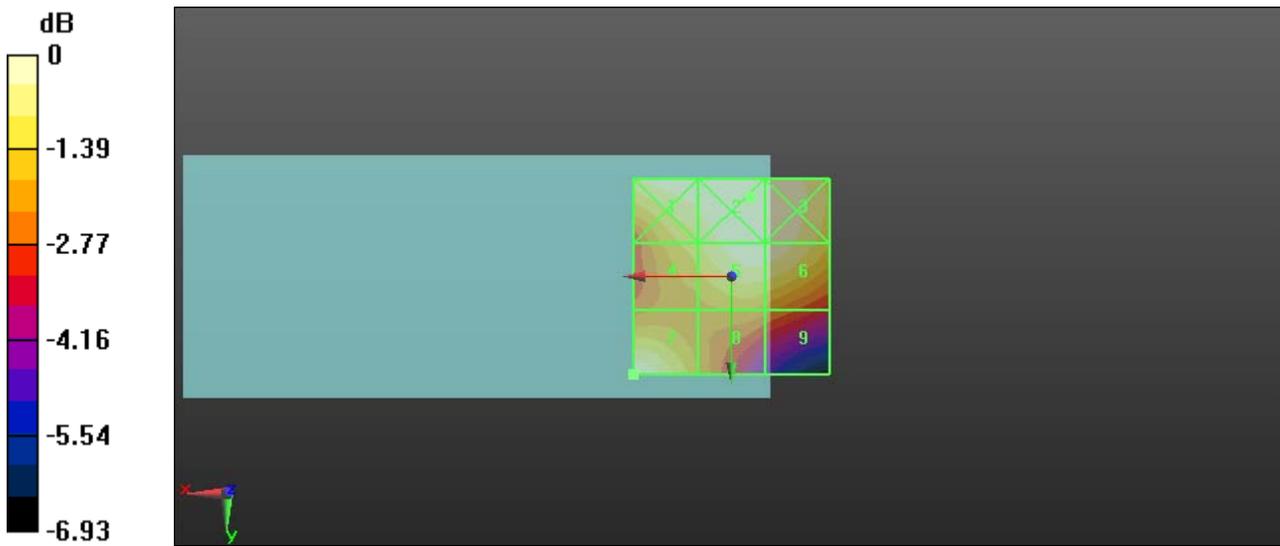
Grid 1 0.091 M4	Grid 2 0.093 M4	Grid 3 0.092 M4
Grid 4 0.080 M4	Grid 5 0.090 M4	Grid 6 0.090 M4
Grid 7 0.091 M4	Grid 8 0.073 M4	Grid 9 0.071 M4

Cursor:

Total = 0.093 A/m

H Category: M4

Location: -5, -20.5, 8.7 mm



0 dB = 0.090A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1880 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 PCS band_open_H Scan/M ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.085 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.087 A/m; Power Drift = -0.04 dB

Hearing Aid Near-Field Category: **M4 (AWF 0 dB)**

Peak H-field in A/m

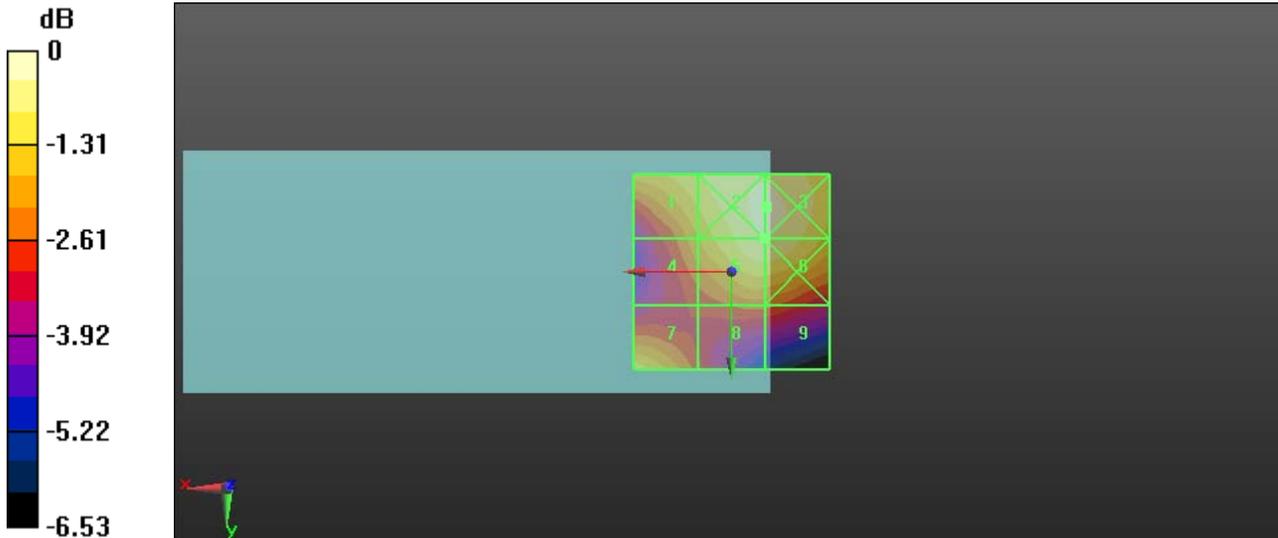
Grid 1 0.081 M4	Grid 2 0.087 M4	Grid 3 0.087 M4
Grid 4 0.074 M4	Grid 5 0.085 M4	Grid 6 0.085 M4
Grid 7 0.081 M4	Grid 8 0.068 M4	Grid 9 0.068 M4

Cursor:

Total = 0.087 A/m

H Category: M4

Location: -9, -16.5, 8.7 mm



0 dB = 0.090 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 PCS band_open_H Scan/H ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.084 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.087 A/m; Power Drift = -0.25 dB

Hearing Aid Near-Field Category: **M4 (AWF 0 dB)**

Peak H-field in A/m

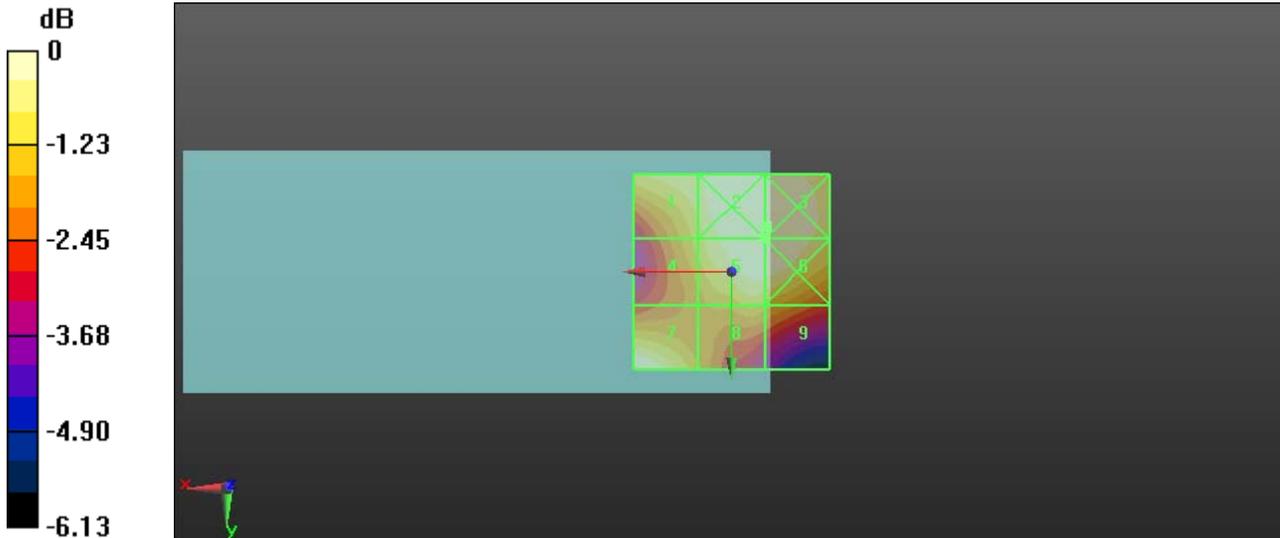
Grid 1 0.076 M4	Grid 2 0.085 M4	Grid 3 0.085 M4
Grid 4 0.071 M4	Grid 5 0.084 M4	Grid 6 0.084 M4
Grid 7 0.083 M4	Grid 8 0.070 M4	Grid 9 0.068 M4

Cursor:

Total = 0.085 A/m

H Category: M4

Location: -9, -11.5, 8.7 mm



0 dB = 0.080 A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011

- Sensor-Surface: (Fix Surface)

- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010

- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB

- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 PCS band_closed_H Scan/L ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.084 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.085 A/m; Power Drift = -0.28 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

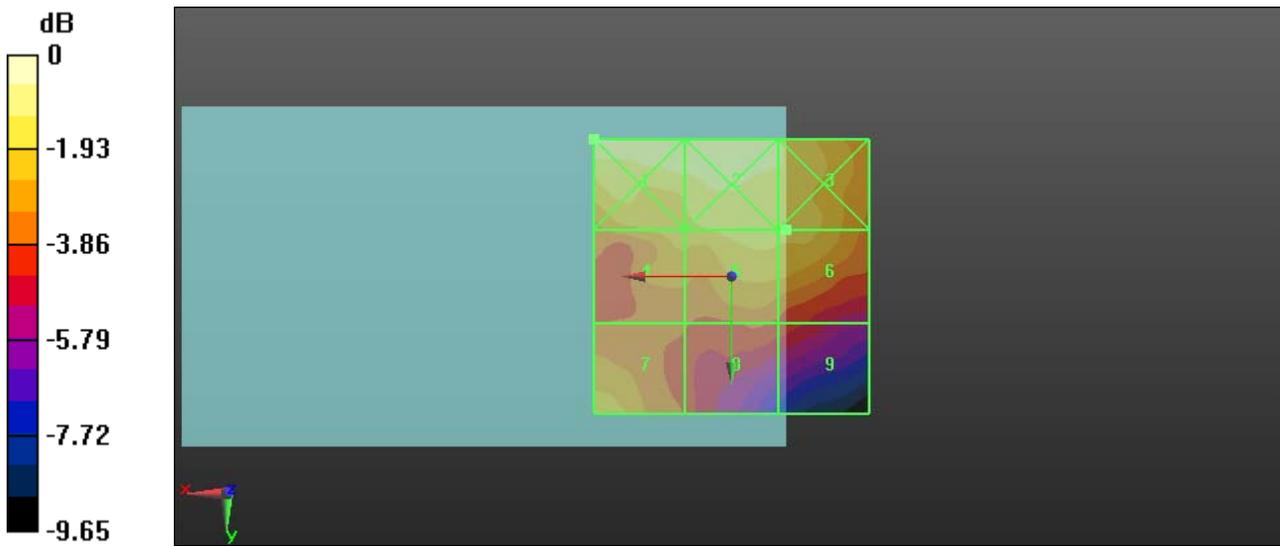
Grid 1 0.097 M4	Grid 2 0.091 M4	Grid 3 0.087 M4
Grid 4 0.077 M4	Grid 5 0.083 M4	Grid 6 0.084 M4
Grid 7 0.081 M4	Grid 8 0.065 M4	Grid 9 0.063 M4

Cursor:

Total = 0.097 A/m

H Category: M4

Location: 25, -25, 8.7 mm



0 dB = 0.100A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1880 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 PCS band_closed_H Scan/M ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.096 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.095 A/m; Power Drift = -0.37 dB

Hearing Aid Near-Field Category: **M4 (AWF 0 dB)**

Peak H-field in A/m

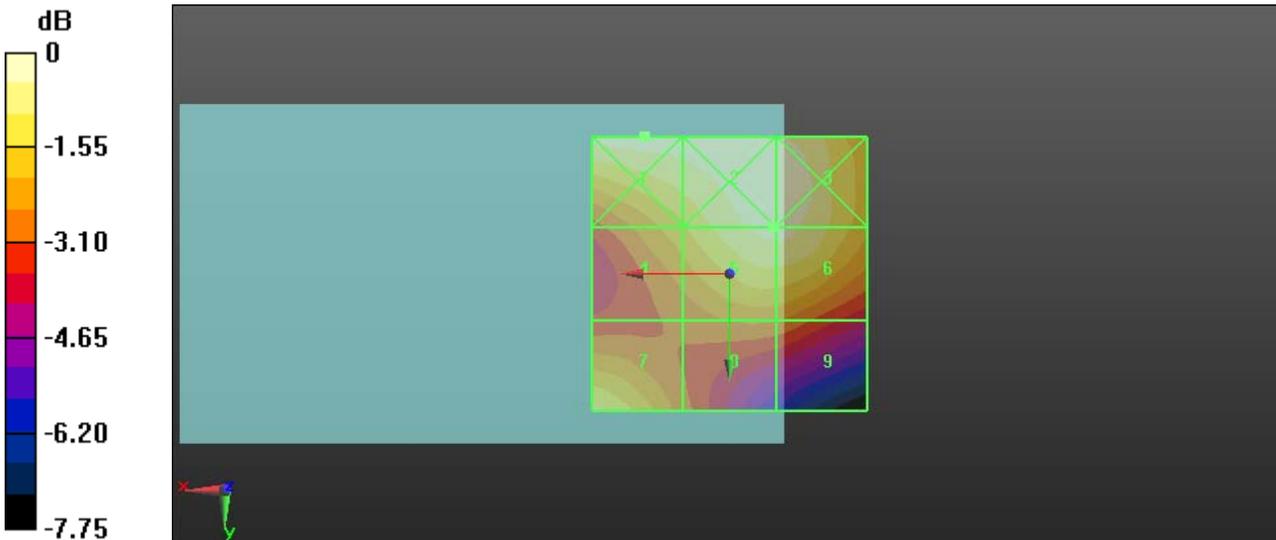
Grid 1 0.098 M4	Grid 2 0.098 M4	Grid 3 0.098 M4
Grid 4 0.083 M4	Grid 5 0.096 M4	Grid 6 0.096 M4
Grid 7 0.091 M4	Grid 8 0.075 M4	Grid 9 0.075 M4

Cursor:

Total = 0.098 A/m

H Category: M4

Location: 15.5, -25, 8.7 mm



0 dB = 0.100A/m

Test Laboratory: UL CCS

HAC RF Emission

Communication System: CDMA PCS Band; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Phantom section: TCoil Section

DASY4 Configuration:

- Probe: H3DV6 - SN6157; ; Calibrated: 1/25/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn1239; Calibrated: 11/17/2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BB
- Measurement SW: DASY52, Version 52.6 (1); SEMCAD X Version 14.4.2 (2595)

CDMA2000 PCS band_closed_H Scan/H ch_H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.087 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.084 A/m; Power Drift = 0.16 dB

Hearing Aid Near-Field Category: **M4 (AWF 0 dB)**

Peak H-field in A/m

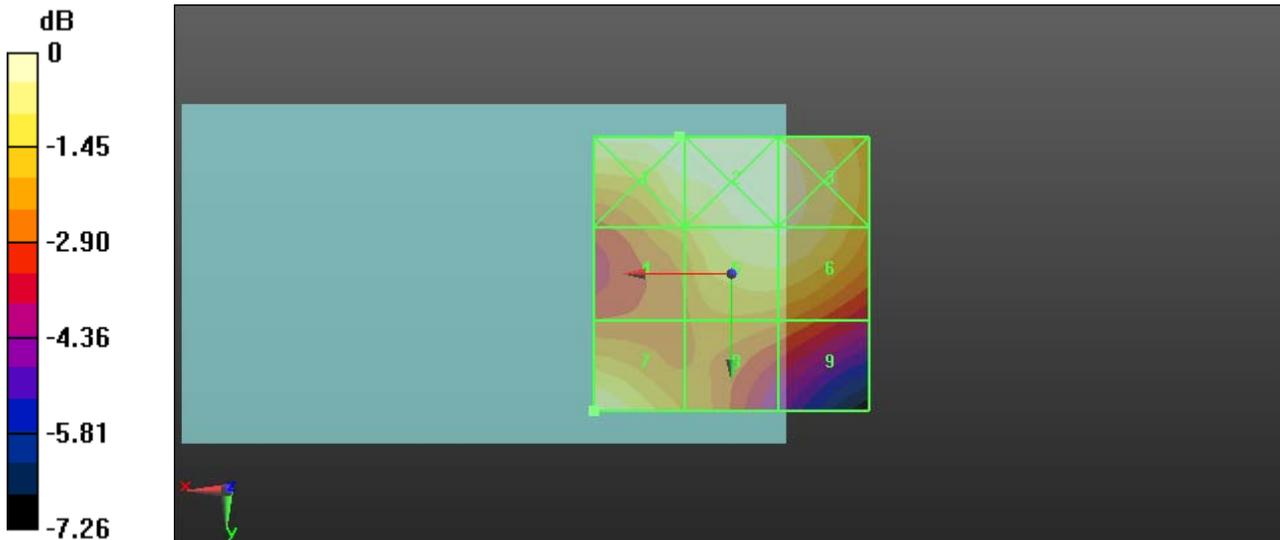
Grid 1 0.091 M4	Grid 2 0.091 M4	Grid 3 0.087 M4
Grid 4 0.077 M4	Grid 5 0.086 M4	Grid 6 0.086 M4
Grid 7 0.087 M4	Grid 8 0.072 M4	Grid 9 0.069 M4

Cursor:

Total = 0.091 A/m

H Category: M4

Location: 9.5, -25, 8.7 mm



0 dB = 0.090A/m